





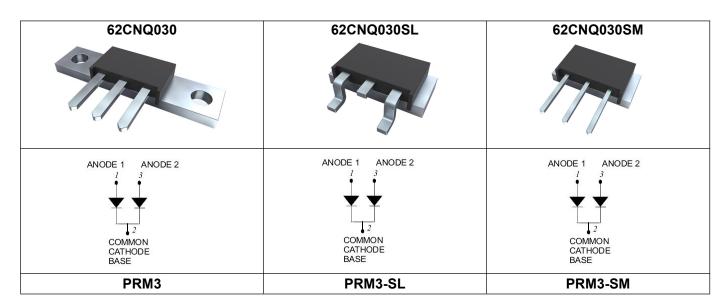
## **62CNQ030 SCHOTTKY RECTIFIER**

#### **Applications**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

#### **Features**

- 150°C T<sub>J</sub> operation
- Center tap module
- Very Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Low profile, high current package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request



## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \end{array}$	-	30	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =135°C, rectangular wave form	30(Per Leg) 60(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	940	Α
Non-Repetitive Avalanche Energy (Peg leg)	Eas	T <sub>J</sub> =25℃,I <sub>AS</sub> =6A,L=1.5mH	27	mJ
Repetitive Avalanche Current(Peg leg)	I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu$ sec Frequency limited by $T_J$ max. $V_A$ =1.5 $\times$ V $_R$ typical	6	А

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop (Per leg) *	V <sub>F1</sub>	@ 30A, Pulse, T <sub>J</sub> = 25 °C @ 60A, Pulse, T <sub>J</sub> = 25 °C	0.45 0.50	0.49 0.53	V
	V <sub>F2</sub>	@ 30A, Pulse, T <sub>J</sub> = 125 °C @ 60A, Pulse, T <sub>J</sub> = 125 °C	0.36 0.41	0.39 0.44	V
Reverse Current (Per leg) *	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 25 °C	0.17	5	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> T <sub>J</sub> = 125 °C	38	280	mA
Junction Capacitance (Per leg)	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	2800	3700	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

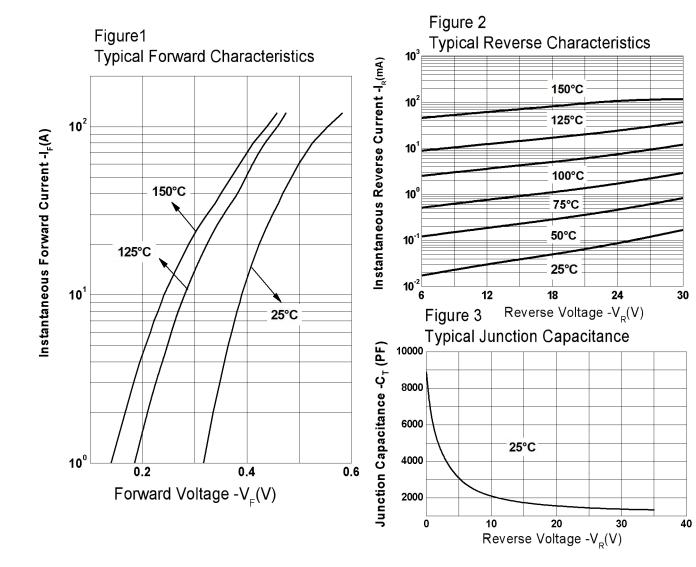
Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +150	°C	
Storage Temperature	$T_{stg}$	-	-55 to +150	°C	
Typical Thermal Resistance Junction to Case (per leg)	$R_{ heta JC}$	DC operation	0.5	°C/W	
Typical Thermal Resistance Junction to Case (per package)	$R_{ heta JC}$	DC operation	0.25	°C/W	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.21	°C/W	
Mounting Torque	ТМ		40(min)	Kg-cm	
I woulding Torque	I IVI	-	58(max)		
Case Style	PRM3 PRM3-SL PRM3-SM				



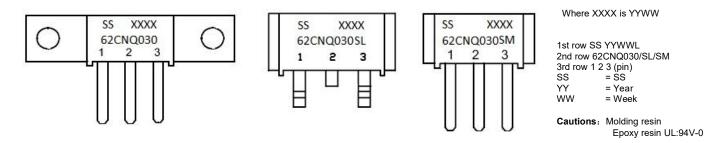




#### **Ratings and Characteristics Curves**



### **Marking Diagram**



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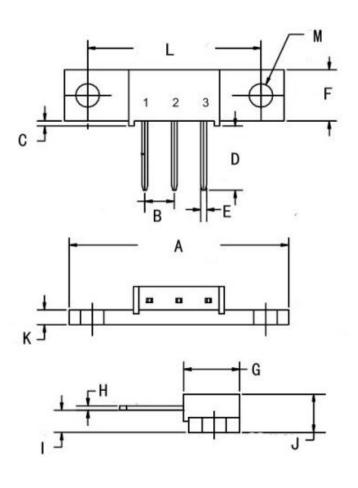




## **Ordering Information**

Device	Package	Approximate Weight(g)	Terminals finish	Baseplate finish	Shipping
62CNQ030	PRM3	8.6	Nickel plated	Nickel plated	48pcs / box
62CNQ030S2	PRM3	8.6	Pure Sn dipped (dipped heigh 6-8mm) Nickel plated		48pcs / box
62CNQ030SL	PRM3-SL	5.3	Pure Sn plated	Pure Sn plated	100pcs / box
62CNQ030SM	PRM3-SM	5.6	Nickel plated	Nickel plated	48pcs / box
62CNQ030SMS2	PRM3-SM	5.6	Pure Sn dipped (dipped heigh 6-8mm)	Nickel plated	48pcs / box

### **Mechanical Dimensions PRM3 (Inches/Millimeters)**



SYMBOL	MillImeters		Inches		
STIVIBOL	Min.	Max.	Min.	Max.	
Α	37.72	38.23	1.485	1.506	
В	5.	08	0.200		
С	0.62	1.02	0.024	0.040	
D	10.38	12.98	0.408	0.511	
E	0.88	1.22	0.034	0.048	
F	8.46	9.06	0.333	0.357	
G	9.24	9.85	0.363	0.388	
Н	0.61	0.92	0.024	0.037	
I	3.19	4.19	0.125	0.165	
J	6.95	7.55	0.273	0.298	
К	2.40	2.60	0.094	0.103	
L	29.51	30.40	1.161	1.197	
М	3.75	4.33	0.147	0.171	

<sup>•</sup> China - Germany - Korea - Singapore - United States •

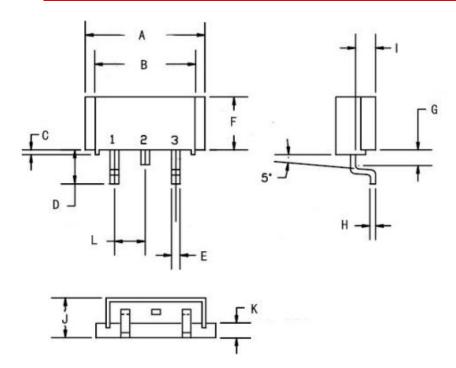
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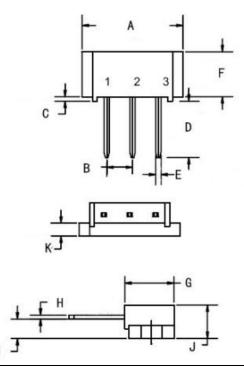


# **Mechanical Dimensions PRM3-SL (Inches/Millimeters)**



SYMBOL	MillImeters		Inches		
OTWIDOL	Min.	Max.	Min.	Max.	
А	19.70	20.30	0.776	0.799	
В	16.51	17.02	0.650	0.670	
С	0.62	1.02	0.024	0.040	
D	4.97	5.97	0.196	0.235	
E	0.88	1.22	0.034	0.048	
F	8.46	9.06	0.333	0.357	
G	2.04	2.54	0.080	0.100	
Н	0.61	0.92	0.024	0.037	
I	3.19	4.19	0.125	0.165	
J	6.95	7.55	0.274	0.297	
К	2.21	2.71	0.087	0.106	
L	5.08		0.200		

## **Mechanical Dimensions PRM3-SM (Inches/Millimeters)**



SYMBOL	MillImeters		Inches	
	Min.	Max.	Min.	Max.
Α	19.70	20.30	0.776	0.799
В	5.08		0.200	
С	0.62	1.02	0.024	0.040
D	10.38	12.98	0.408	0.511
E	0.88	1.22	0.034	0.048
F	8.46	9.06	0.333	0.357
G	9.24	9.85	0.363	0.388
Н	0.61	0.92	0.024	0.037
I	3.19	4.19	0.125	0.165
J	6.95	7.55	0.273	0.298
К	2.40	2.60	0.094	0.103

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